



STAC3932F

RF power transistors HF/VHF/UHF N-channel MOSFETs

Preliminary data

Features

- Excellent thermal stability
- Common source push-pull configuration
- POUT = 580 W typ. with 24.6 dB gain @ 123 MHz
- In compliance with the 2002/95/EC European directive

Description

The STAC3932F is a N-channel MOS field-effect RF power transistor. It is intended for use in 100 V DC large signal applications up to 250 MHz.



Figure 1. Pin connection

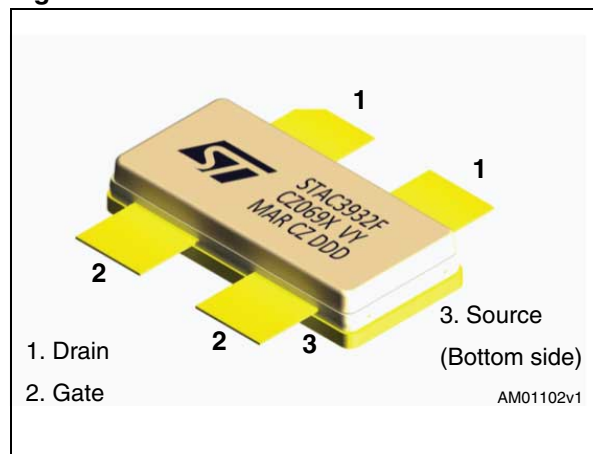


Table 1. Device summary

| Order code | Marking | Package | Packaging |
|------------|-----------|----------|--------------|
| STAC3932F | STAC3932F | STAC244F | Plastic tray |

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1 Electrical data

1.1 Maximum ratings

Table 2. Absolute maximum ratings ($T_{CASE} = 25\text{ °C}$)

| Symbol | Parameter | Value | Unit |
|---------------------|--|-------------|--------------------|
| $V_{(BR)DSS}^{(1)}$ | Drain source voltage | 250 | V |
| V_{DGR} | Drain-gate voltage ($R_{GS} = 1\text{ M}\Omega$) | 250 | V |
| V_{GS} | Gate-source voltage | ± 20 | V |
| I_D | Drain current | 20 | A |
| P_{DISS} | Power dissipation | 625 | W |
| T_J | Max. operating junction temperature | 200 | $^{\circ}\text{C}$ |
| T_{STG} | Storage temperature | -65 to +150 | $^{\circ}\text{C}$ |

1. $T_J = 150\text{ °C}$

1.2 Thermal data

Table 3. Thermal data

| Symbol | Parameter | Value | Unit |
|------------|------------------------------------|-------|----------------------|
| R_{thJC} | Junction - case thermal resistance | 0.28 | $^{\circ}\text{C/W}$ |

2 Electrical characteristics

($T_{CASE} = 25\text{ }^{\circ}\text{C}$)

2.1 Static

Table 4. Static (per side)

| Symbol | Test conditions | | Min. | Typ. | Max. | Unit |
|---------------------|------------------------|--------------------------|------|------|------|------|
| $V_{(BR)DSS}^{(1)}$ | $V_{GS} = 0\text{ V}$ | $I_{DS} = 100\text{ mA}$ | 250 | | | V |
| I_{DSS} | $V_{GS} = 0\text{ V}$ | $V_{DS} = 100\text{ V}$ | | | 1 | mA |
| I_{GSS} | $V_{GS} = 20\text{ V}$ | $V_{DS} = 0\text{ V}$ | | | 250 | nA |
| V_{TH} | $V_{DS} = 10\text{ V}$ | $I_D = 250\text{ mA}$ | 2.0 | | 4.0 | V |
| $V_{DS(ON)}$ | $V_{GS} = 10\text{ V}$ | $I_D = 5\text{ A}$ | | 2.5 | 3.5 | V |
| G_{FS} | $V_{DS} = 10\text{ V}$ | $I_D = 2.5\text{ A}$ | 3.0 | | 5.0 | S |
| C_{ISS} | $V_{GS} = 0\text{ V}$ | $V_{DS} = 100\text{ V}$ | | 492 | | pF |
| C_{OSS} | $V_{GS} = 0\text{ V}$ | $V_{DS} = 100\text{ V}$ | | 134 | | pF |
| C_{RSS} | $V_{GS} = 0\text{ V}$ | $V_{DS} = 100\text{ V}$ | | 5.2 | | pF |

1. $T_J = 150\text{ }^{\circ}\text{C}$

2.2 Dynamic

Table 5. CW

| Symbol | Test conditions | Min. | Typ. | Max. | Unit |
|-----------|--|------|------|------|------|
| P_{OUT} | $V_{DD} = 100\text{ V}$, $I_{DQ} = 2 \times 250\text{ mA}$, $P_{IN} = 2\text{ W}$, $f = 123\text{ MHz}$ | 450 | 580 | | W |
| h_D | $V_{DD} = 100\text{ V}$, $I_{DQ} = 2 \times 250\text{ mA}$, $P_{IN} = 2\text{ W}$, $f = 123\text{ MHz}$ | | 70 | | % |

Table 6. Pulse / 1 mec -- 10 %

| Symbol | Test conditions | Min. | Typ. | Max. | Unit |
|-----------|--|------|------|------|------|
| P_{OUT} | $V_{DD} = 100\text{ V}$, $I_{DQ} = 2 \times 250\text{ mA}$, $P_{IN} = 8\text{ W}$, $f = 123\text{ MHz}$ | | 900 | | W |
| h_D | $V_{DD} = 100\text{ V}$, $I_{DQ} = 2 \times 250\text{ mA}$, $P_{IN} = 8\text{ W}$, $f = 123\text{ MHz}$ | | 65 | | % |

3 Impedances

Figure 2. Impedance data

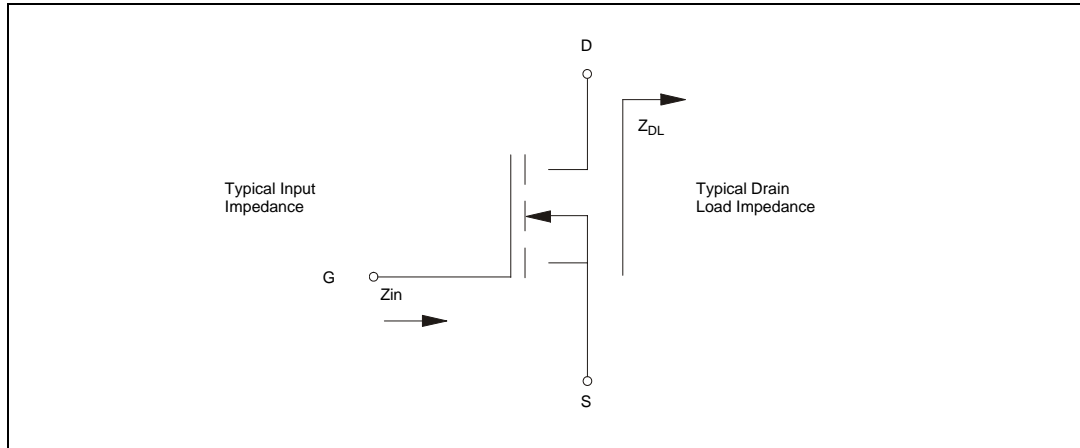
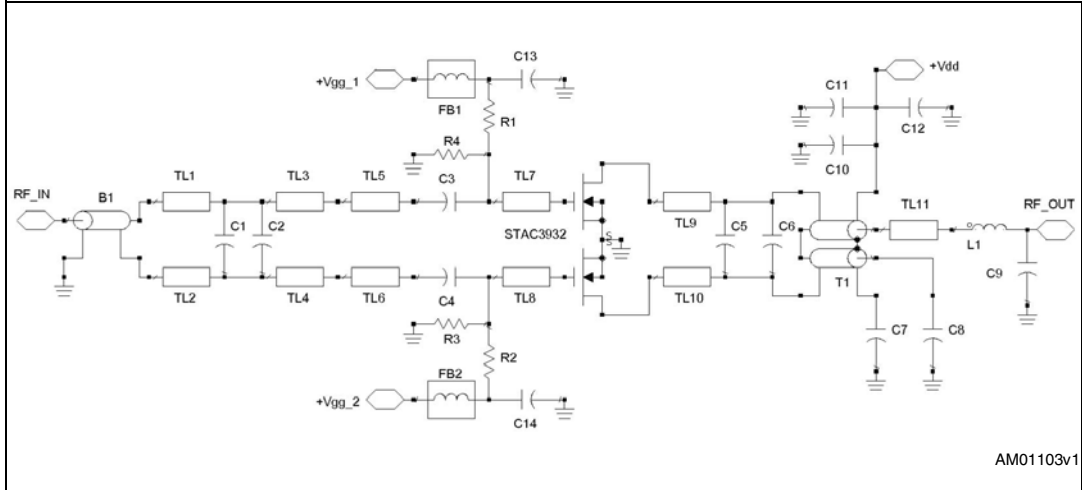


Table 7. Impedance data

| Freq. | Z_{IN} (Ω) | Z_{DL} (Ω) |
|-----------------|-----------------------|-----------------------|
| 123 MHz (Pulse) | $1.0 - j 4.80$ | $6.3 + j 10.5$ |
| 123 MHz (CW) | $0.8 - j 3.45$ | $5.0 + j 13.0$ |
| 64 MHz | $1.4 - j 10.0$ | $12.8 + j 14.0$ |

4 Electrical schematic and BOM

Figure 3. Electrical schematic



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Table 8. Bill of materials

| Component | Description |
|-----------|--|
| C1 | 270 pF ATC 100B chip capacitor |
| C2 | 180 pF ATC 100B chip capacitor |
| C3, C4 | 750 pF ATC 700B chip capacitor |
| C5, C8 | 43 pF ATC 100B chip capacitor |
| C6 | 20 pF ATC 100B chip capacitor |
| C7 | 1000 pF ATC 100C chip capacitor |
| C9 | 5.6 pF ATC 100B chip capacitor |
| C10 | 2200 pF ATC 100C chip capacitor |
| C11 | 470 pF ATC 100B chip capacitor |
| C12 | 100 μF, 200 V electrolytic capacitor |
| C13, C14 | 1200 pF ATC 700B chip capacitor |
| R1, R2 | 15 Ω 1/4 watt chip resistor |
| R3, R4 | 30 Ω 1/4 watt axial lead resistor |
| L1 | 3 turns, 16 ga magnet wire, Id 3/8", .165" turn spacing, 78 nH |
| FB1, FB2 | ferrite bead, Fair-Rite # 2743019447 |
| B1 | 1/4λ balun transformer, RG316-25Ω, 16.5" |
| T1 | 20 ga teflon coated wire thru 4 copper tubes OD 1/8"x 1.5" |
| TL1, TL2 | 0.740" x 0.200" microstrip |
| TL3, TL4 | 0.360" x 0.200" microstrip |

Table 8. Bill of materials (continued)

| Component | Description |
|------------------|----------------------------|
| TL5, TL6 | 0.480" x 0.350" microstrip |
| TL7, TL8 | 0.220" x 0.350" microstrip |
| TL9, TL10 | 0.350" x 0.660" microstrip |
| TL11 | 0.415" x 0.200" microstrip |
| Board | 0.062" FR-4 |

5 Circuit layout

Figure 4. Circuit layout

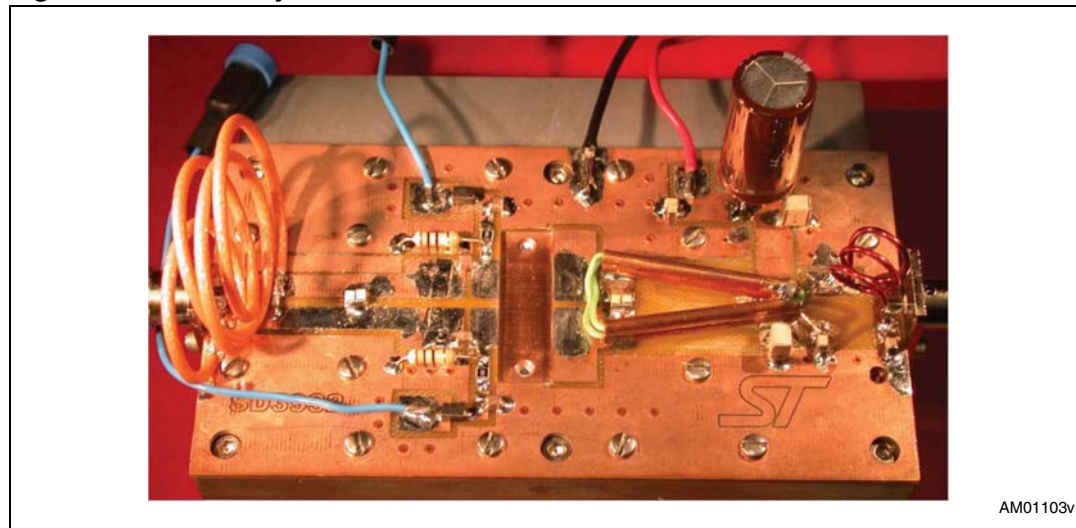
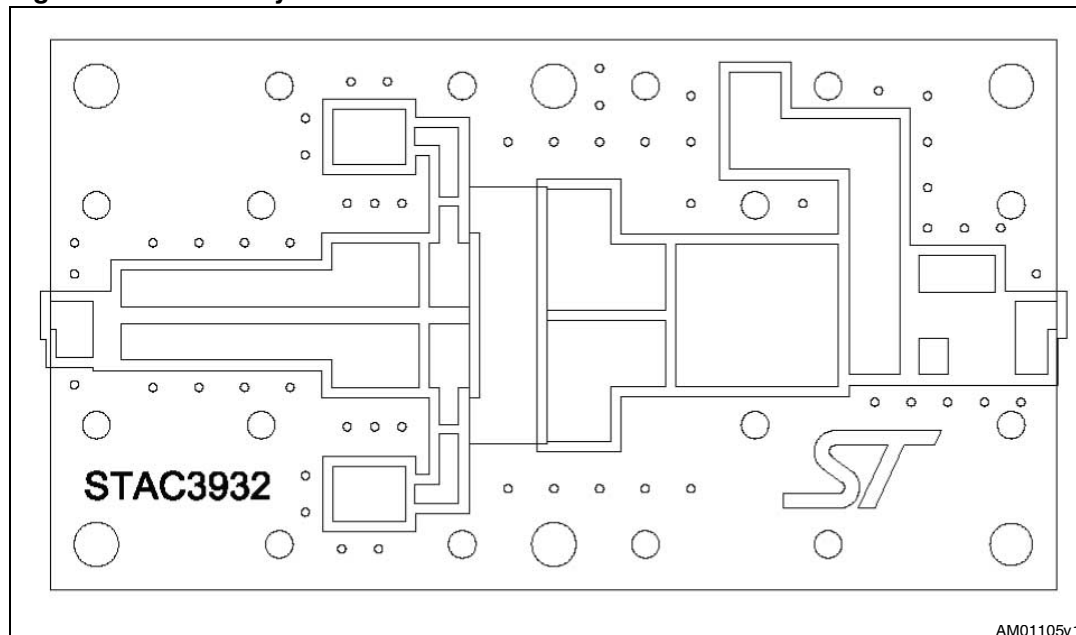


Figure 5. Circuit layout



6 Typical performance

Figure 6. Capacitances vs drain supply voltage

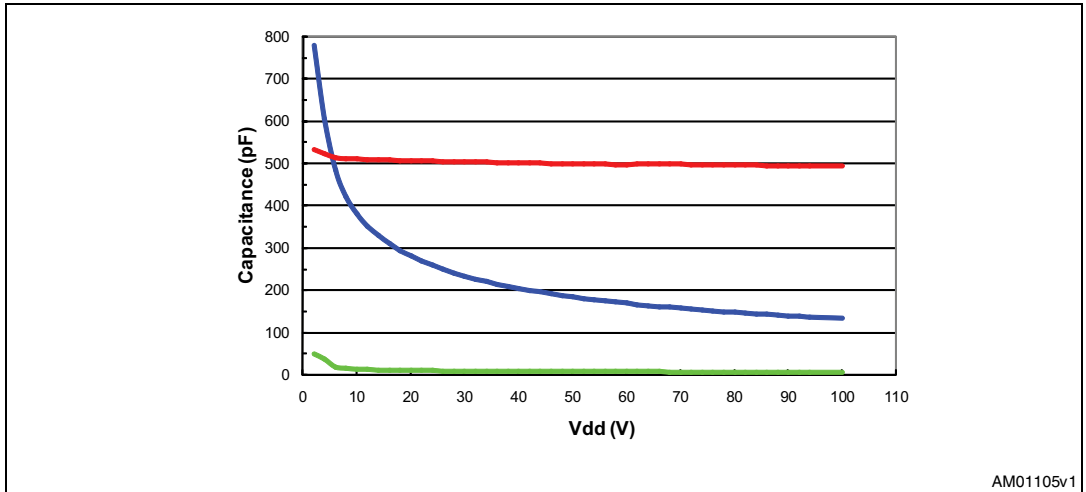


Figure 7. Maximum safe operating area

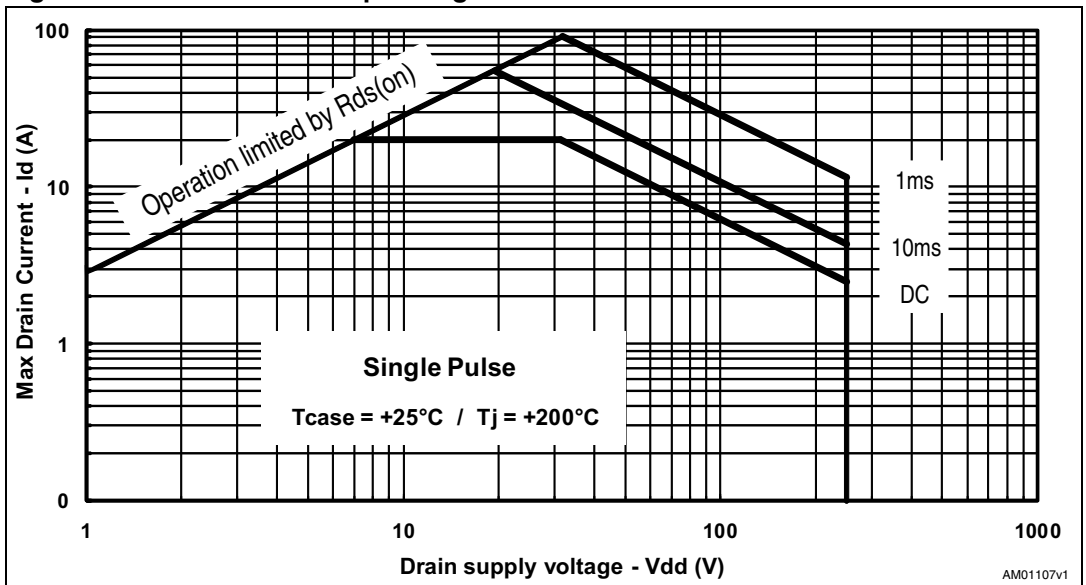


Figure 8. Transient thermal impedance

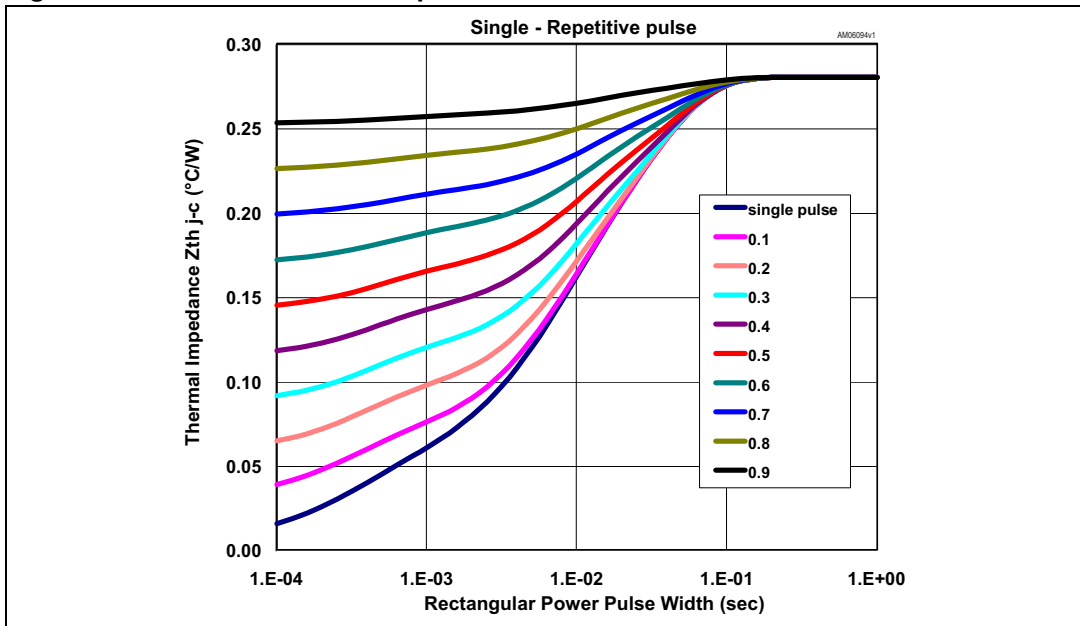


Figure 9. Transient thermal model

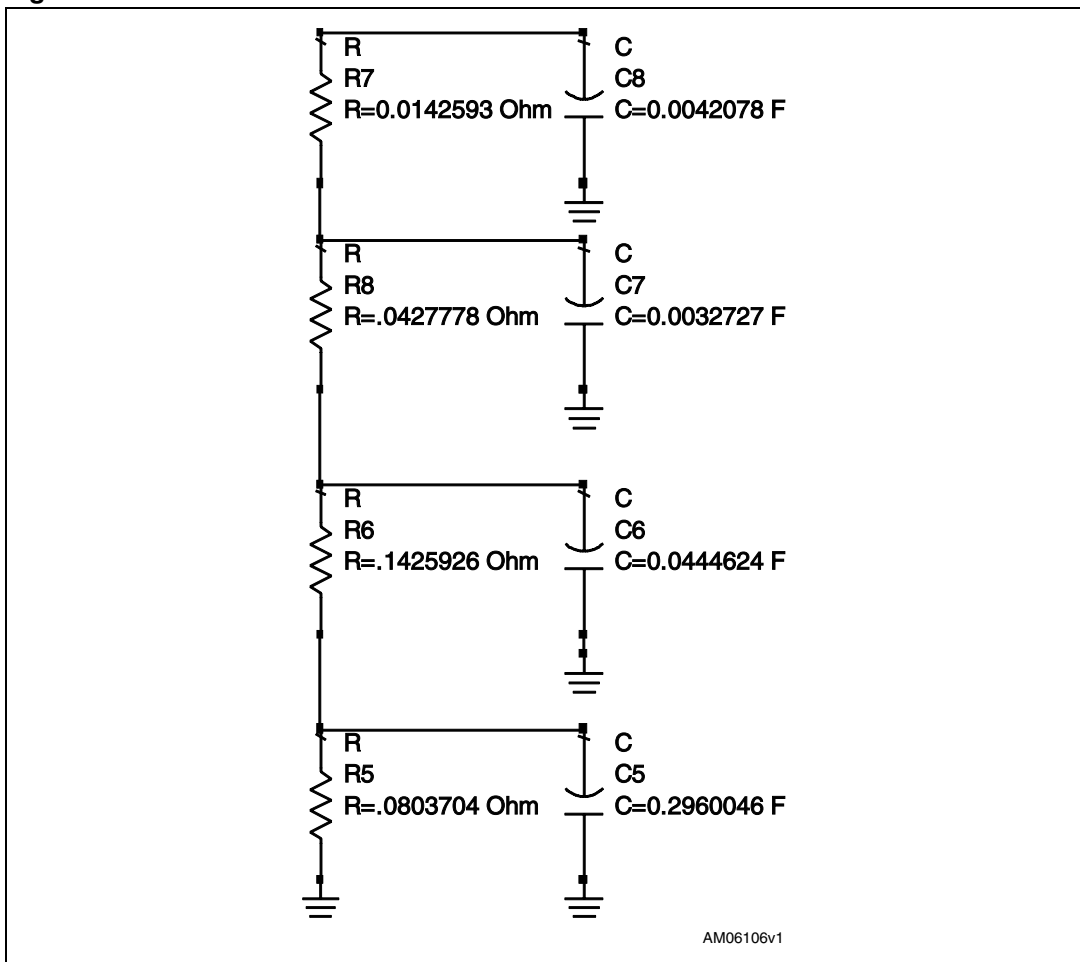
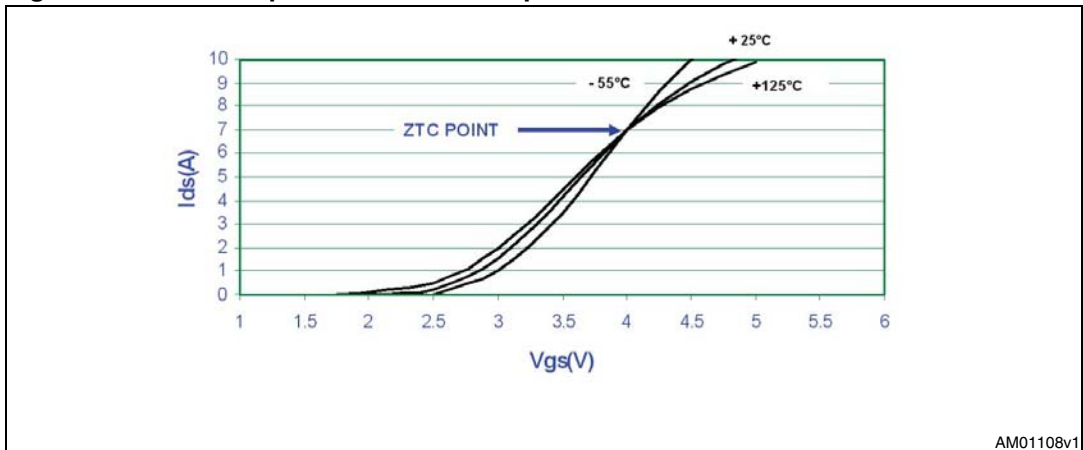
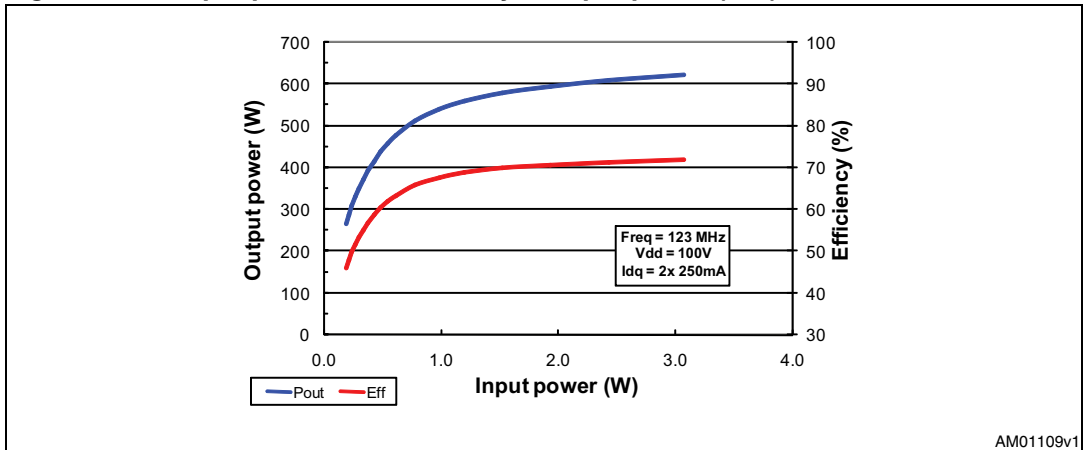


Figure 10. Zero temperature coefficient point



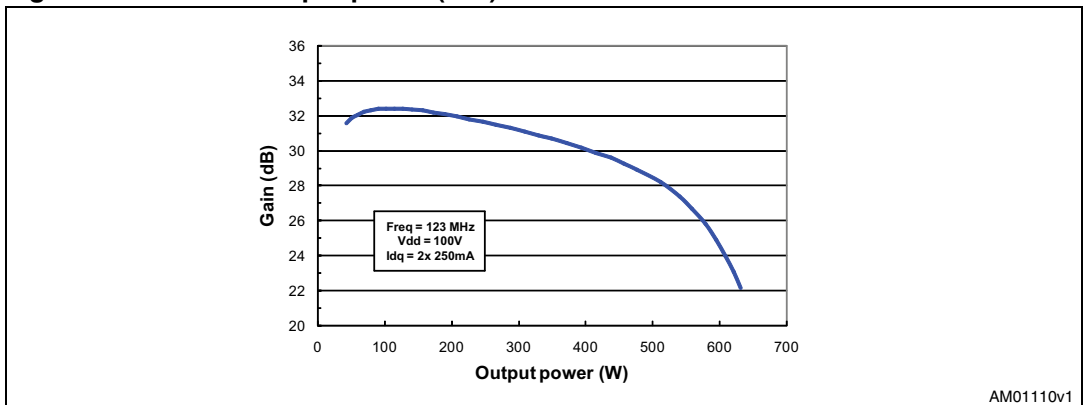
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Figure 11. Output power and efficiency vs input power (CW)



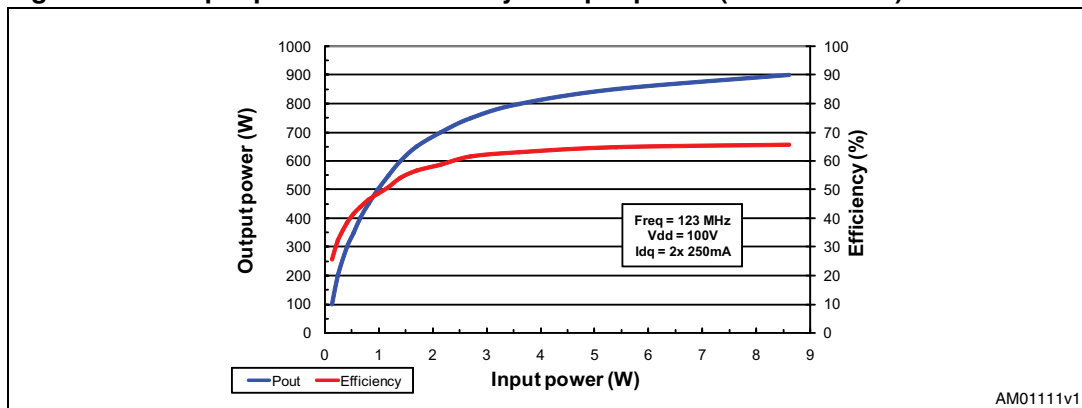
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Figure 12. Gain vs output power (CW)



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Figure 13. Output power and efficiency vs input power (1 msec - 10%)



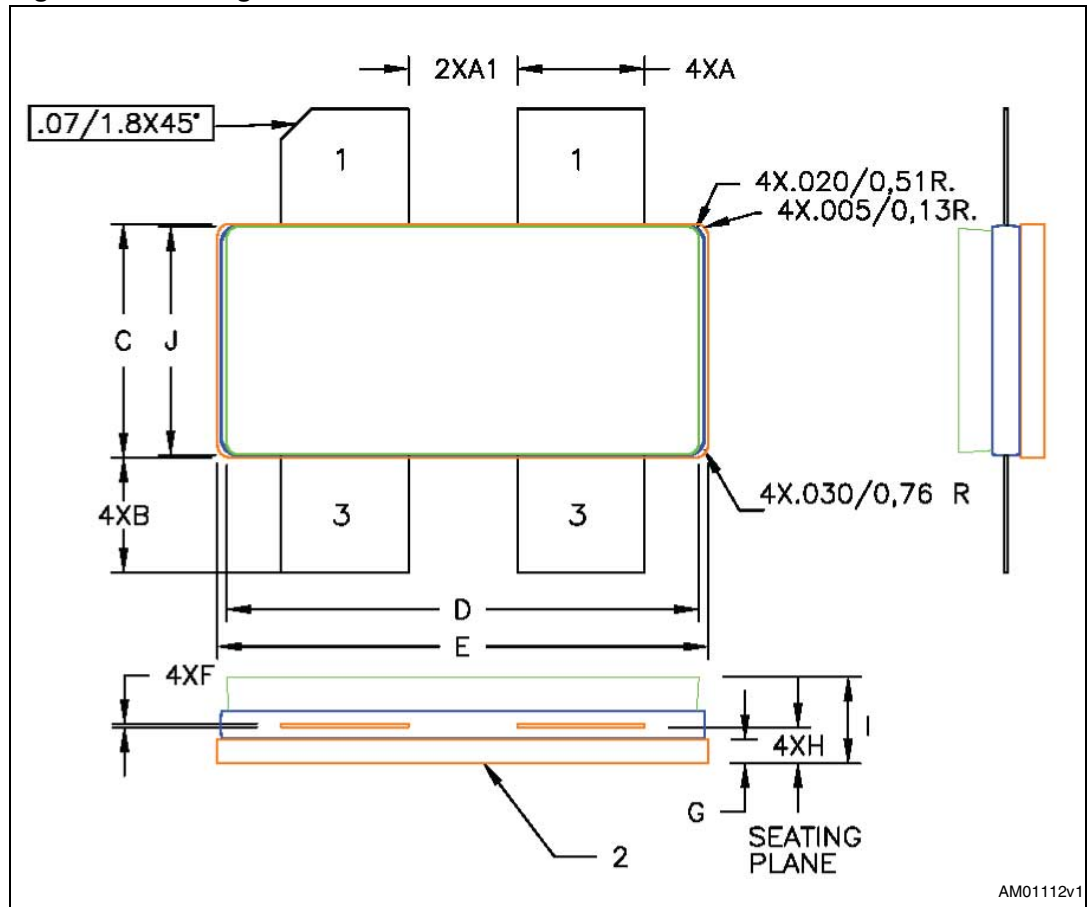
7 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

Table 9. STAC244F package dimensions

| Dim. | mm. | | Inch | |
|------|-------|-------|-------|-------|
| | Min | Max | Min | Max |
| A | 5.10 | 5.59 | 200 | 220 |
| A1 | 4.32 | 4.83 | 170 | 190 |
| B | 4.32 | 5.33 | 170 | 210 |
| C | 9.65 | 9.91 | 380 | 390 |
| D | 19.61 | 20.02 | 772 | 788 |
| E | 20.45 | 20.70 | 805 | 815 |
| F | 0.08 | 1.15 | 0.003 | 0.006 |
| G | 0.89 | 1.14 | 0.035 | 0.045 |
| H | 1.45 | 1.70 | 0.057 | 0.067 |
| I | 3.18 | 4.32 | 0.125 | 0.170 |
| J | 9.27 | 9.53 | 0.365 | 0.375 |

Figure 14. Package dimensions



8 Revision history

Table 10. Document revision history

| Date | Revision | Changes |
|-------------|----------|---|
| 24-Mar-2009 | 1 | First release. |
| 12-Feb-2010 | 2 | <i>Table 1</i> (packaging) modified <i>Figure 1</i> modified. |
| 18-Feb-2010 | 3 | Updated description on cover page. |
| 16-Mar-2010 | 4 | Updated <i>Figure 7: Maximum safe operating area</i> . Added <i>Figure 8: Transient thermal impedance</i> . and <i>Figure 9: Transient thermal model</i> . |

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